## NSN 5962-01-089-1036

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View Online at https://aerobasegroup.com/nsn/5962-01-089-1036 **Body Length:** 0.440 inches **Body Width:** Between 0.240 inches and 0.325 inches **Body Height:** Between 0.045 inches and 0.085 inches **Maximum Power Dissipation Rating:** 910.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output and schottky and high speed and w/enable and w/disable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 82577-932820 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a **Unit Of Measure:** 

Demilitarization: Yes - demil/mli

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